MSC2712GT1G, MSC2712YT1G

General Purpose Amplifier Transistor

NPN Surface Mount

Features

- Moisture Sensitivity Level: 1
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



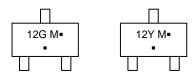
ON Semiconductor®

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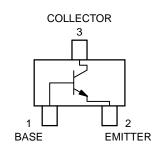


SC-59 CASE 318D STYLE 1

MARKING DIAGRAMS



12M, 12Y = Specific Device Code M = Date Code • = Pb-Free Package (Note: Microdot may be in either location)



ORDERING INFORMATION

Device	Package	Shipping [†]
MSC2712GT1G	SC–59 (Pb–Free)	3000 / Tape & Reel
MSC2712YT1G	SC–59 (Pb–Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	60	Vdc
Collector-Emitter Voltage	V _{(BR)CEO}	50	Vdc
Emitter-Base Voltage	V _{(BR)EBO}	7.0	Vdc
Collector Current – Continuous	Ι _C	100	mAdc
Collector Current – Peak	I _{C(P)}	200	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Power Dissipation	PD	200	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

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Characteristic	Symbol	Min	Max	Unit
Collector–Emitter Breakdown Voltage $(I_C = 2.0 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	50	-	Vdc
Collector–Base Breakdown Voltage $(I_C = 10 \ \mu Adc, I_E = 0)$	V _{(BR)CBO}	60	-	Vdc
Emitter–Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$	V _{(BR)EBO}	7.0	-	Vdc
Collector–Base Cutoff Current ($V_{CB} = 45 \text{ Vdc}, I_E = 0$)	I _{CBO}	-	0.1	μAdc
	I _{CEO}		0.1 2.0 1.0	μAdc μAdc mAdc
	h _{FE} C2712GT1G C2712YT1G	200 120	400 240	-
Collector–Emitter Saturation Voltage $(I_C = 100 \text{ mAdc}, I_B = 10 \text{ mAdc})$	V _{CE(sat)}	-	0.5	Vdc
$\begin{array}{l} Current-Gain-Bandwidth\ Product\\ (I_C=1\ mA,\ V_{CE}=10.0\ V,\ f=10\ MHz) \end{array}$	f _T	50	_	MHz

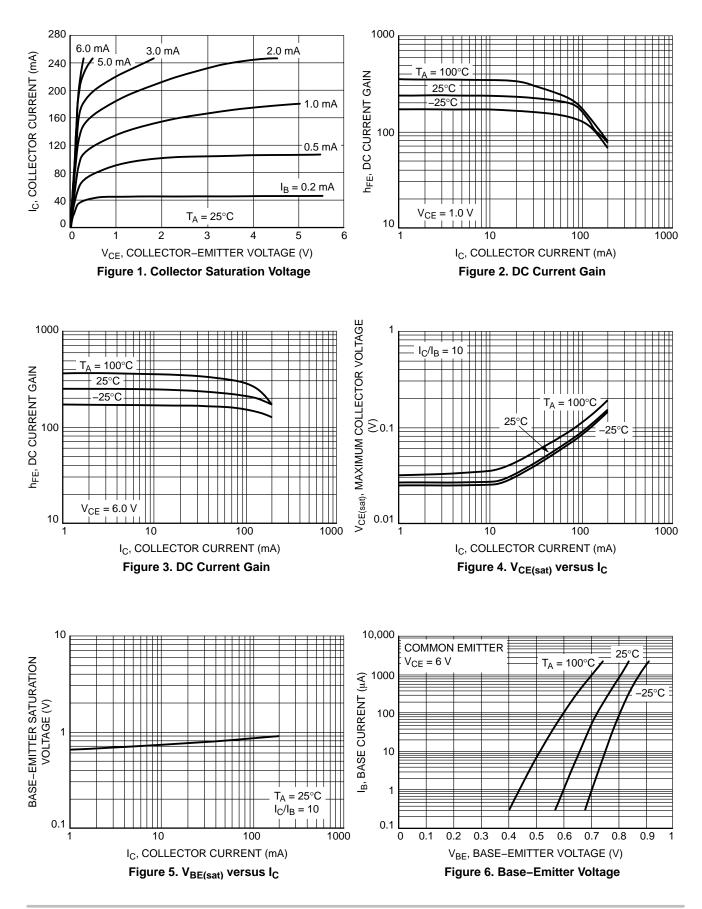
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width \leq 300 $\mu s,\, D.C. \leq$ 2%.

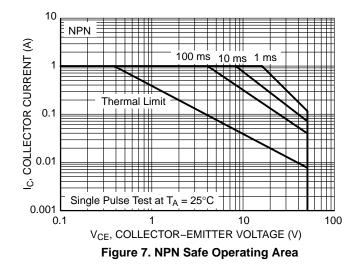
MSC2712GT1G, MSC2712YT1G

TYPICAL ELECTRICAL CHARACTERISTICS

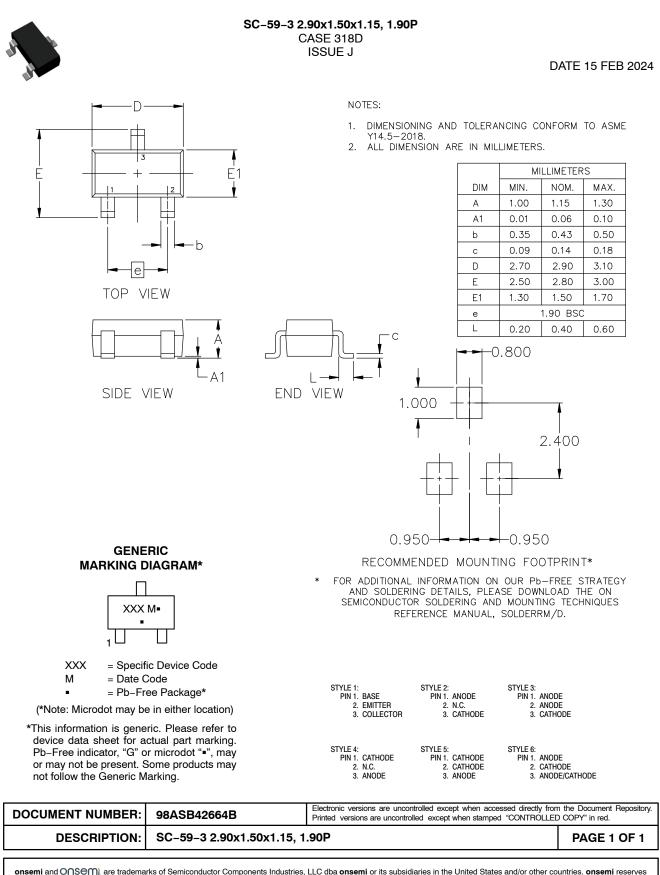


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TYPICAL ELECTRICAL CHARACTERISTICS



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